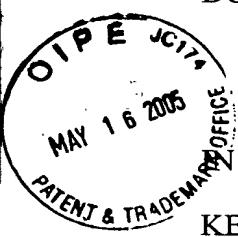


DOCKET NO: 239515US2



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

RE APPLICATION OF

KEISUKE YONEHAMA, ET AL.

SERIAL NO: 10/602,595

FILED: JUNE 25, 2003

FOR: A SEMICONDUCTOR MEMORY  
DEVICE HAVING A GATE ELECTRODE  
AND A DIFFUSION LAYER AND A  
MANUFACTURING METHOD THEREOF

:

: EXAMINER: OWENS, D.

:

: GROUP ART UNIT: 2811

:

AMENDMENT FILED CONCURRENTLY WITH AN RCE

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated February 15, 2005, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Abstract** begin on page 5 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 7 of this paper.

**Remarks** begin on page 14 of this paper.